# NSN 5961-00-998-1539

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Inclosure Material:

Metal

**Overall Length:** 

0.300 inches

# **Overall Diameter:**

0.340 inches

# **Mounting Facility Quantity:**

1

# Internal Configuration:

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

Internal Junction Configuration:

Npn

### **Mounting Method:**

Threaded stud

# Features Provided:

Hermetically sealed case

# **Overall Width Across Flats:**

0.440 inches

# Thread Size:

0.190 inches

# Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

65.0 collector to base voltage/static/emitter open and 40.0 collector to emitter voltage/static/base open and 4.0 emitter to base voltage, static, collector open

### **Current Rating Per Characteristic:**

1.50 amperes source cutoff current

### **Power Rating Per Characteristic:**

11.6 watts small-signal input power, common-collector

### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

# Thread Series Designator:

Unf

### **Terminal Type And Quantity:**

3 pin

Shelf Life:

N/a

### Unit Of Measure:

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#### Demilitarization:

No

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